

DE LA RECHERCHE À L'INDUSTRIE

The logo for CEA (Commissariat à l'énergie atomique et aux énergies alternatives) features the letters 'cea' in a white, lowercase, sans-serif font. A horizontal bar with a green-to-yellow gradient is positioned below the letters.

# S3-LEB@SPIRAL2 physics and status

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IJCLab (Orsay)  
GANIL (Caen)

# SEASON@S<sup>3</sup>-LEB

Spectroscopy Electron Alpha in Silicon bOx couNter

Damien THISSE  
CEA IRFU (Saclay)

Journées du LabEx P2IO  
01-12-2022

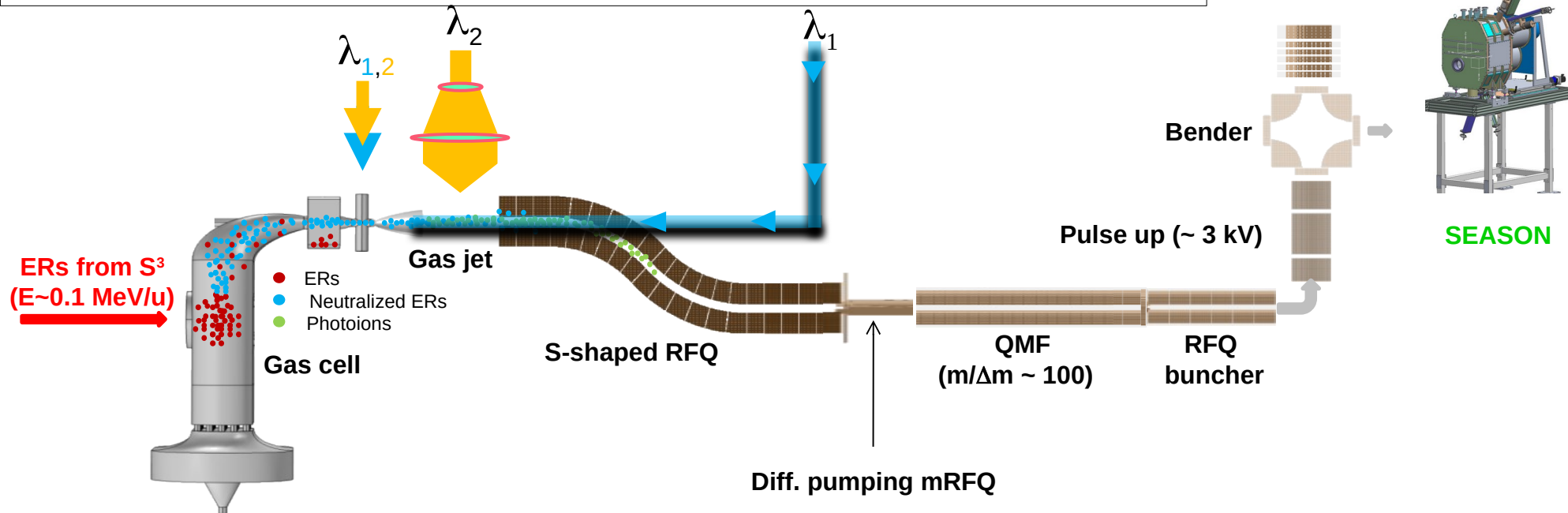
- **SEASON** will be mounted at the end of the S<sup>3</sup>-LEB for the study of HN/SHN

- It will be dedicated to :

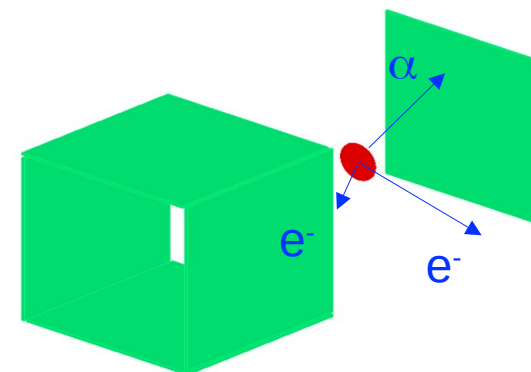
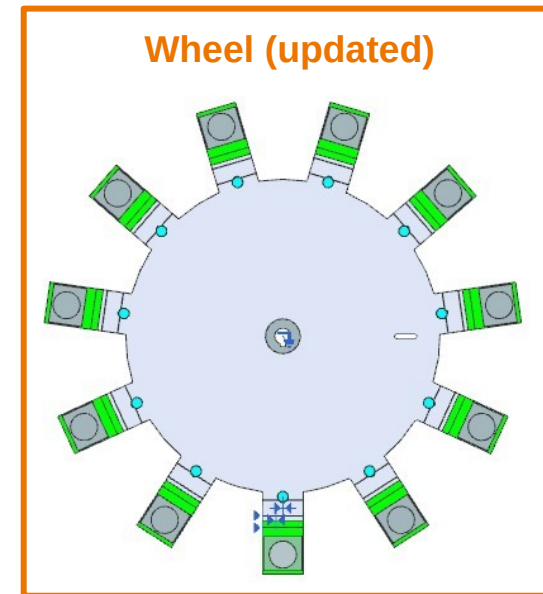
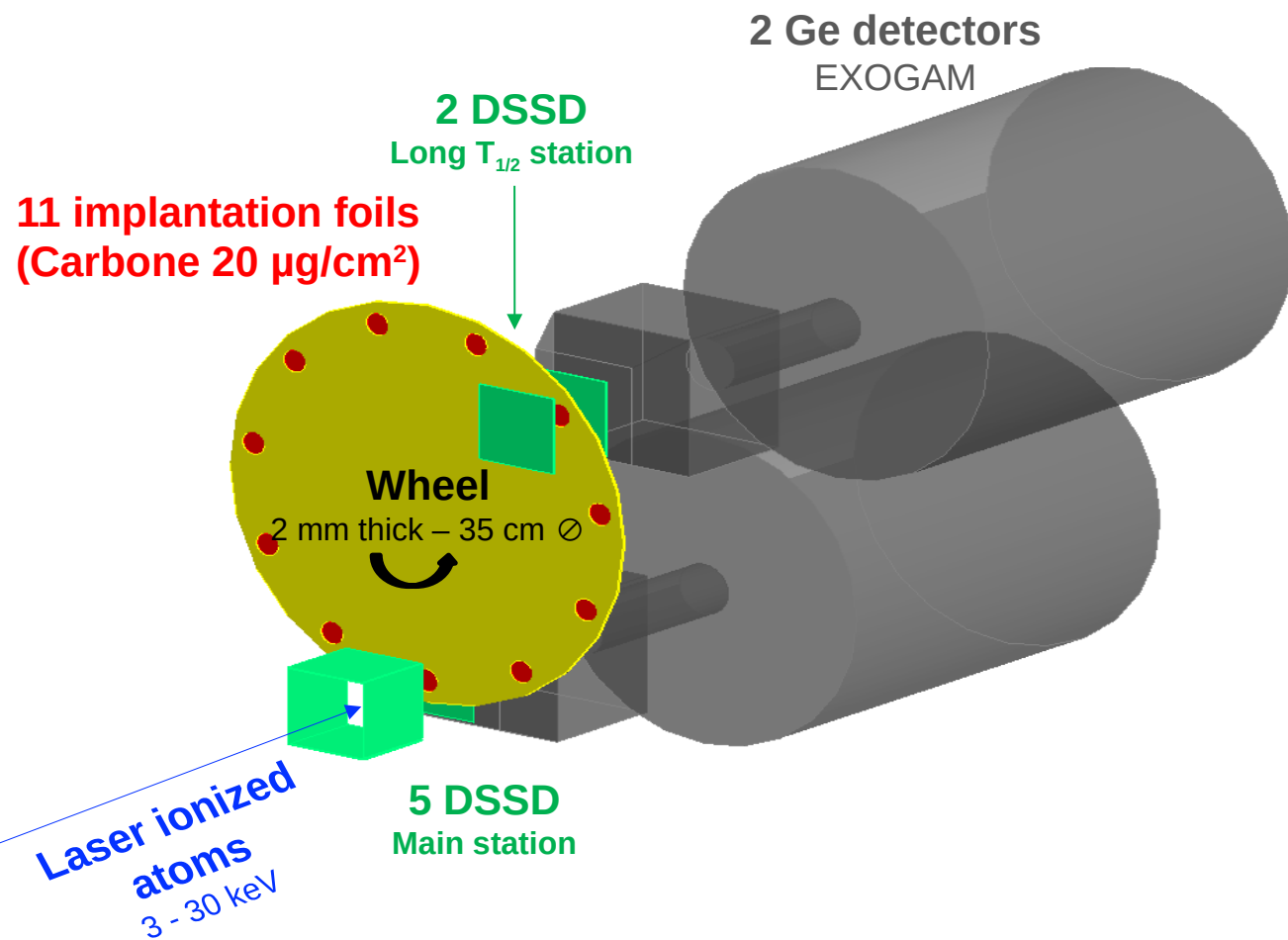
1. Counting laser ionized atoms (laser ionization spectroscopy)
2.  $\alpha$ , electron and  $\gamma$  decay spectroscopy

⇒ **Coupling atomic and nuclear approaches to study HN/SHN produced at S<sup>3</sup>**

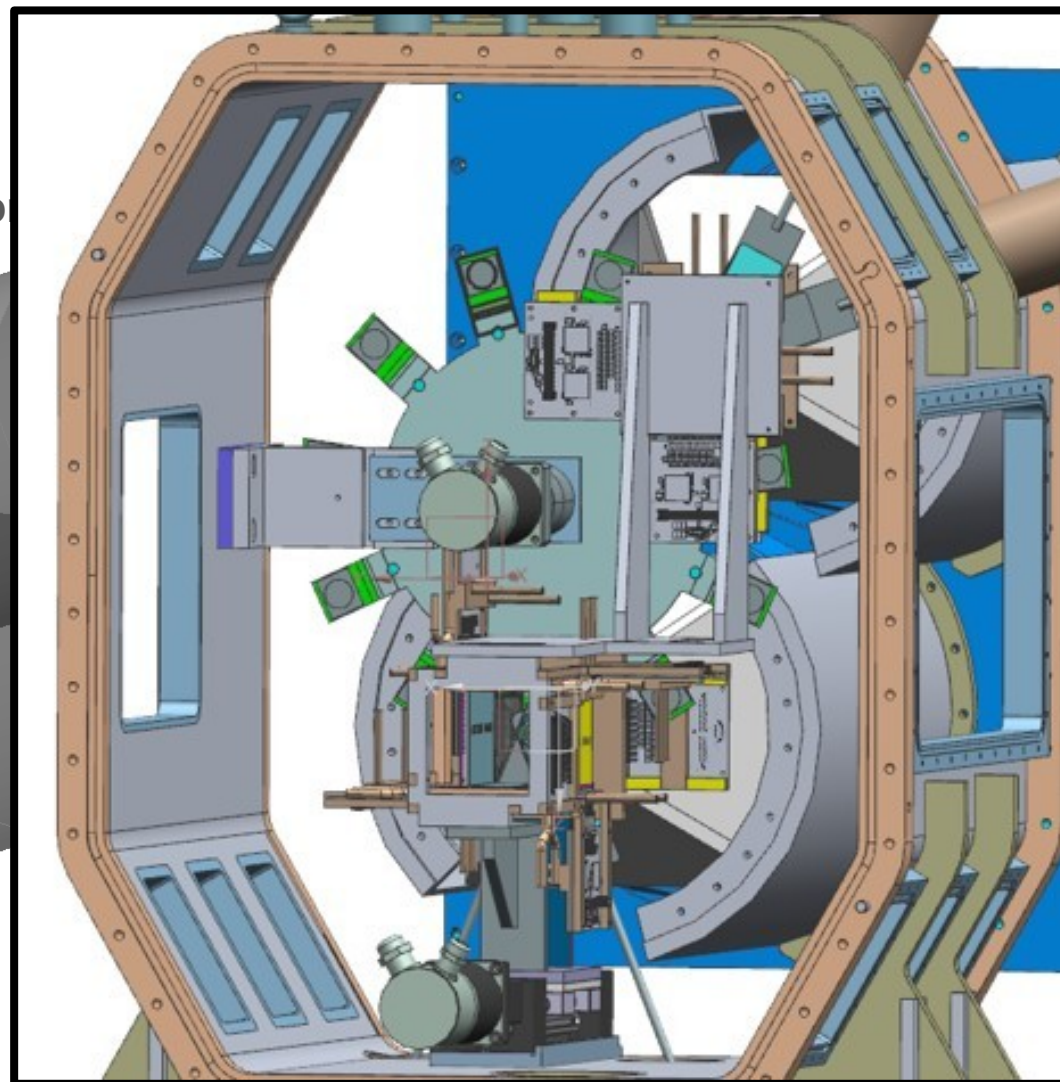
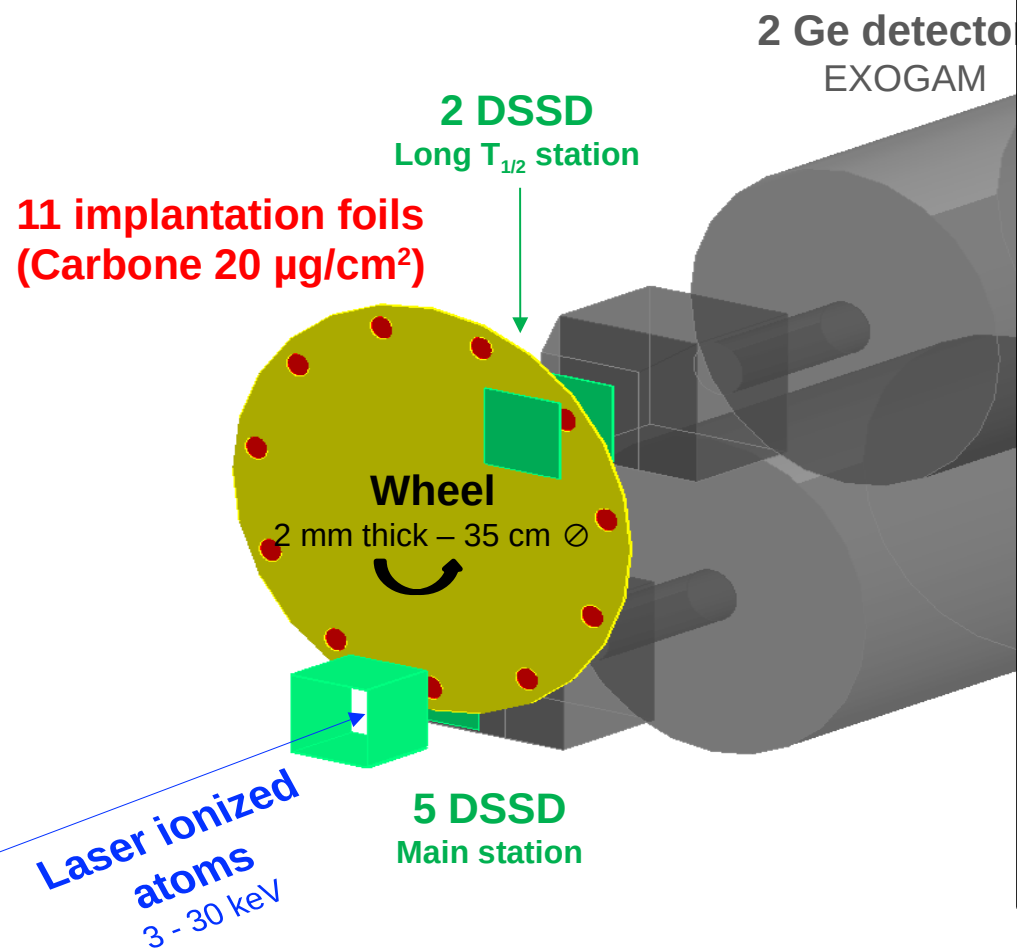
Octupolar deformation  
SHN structure study



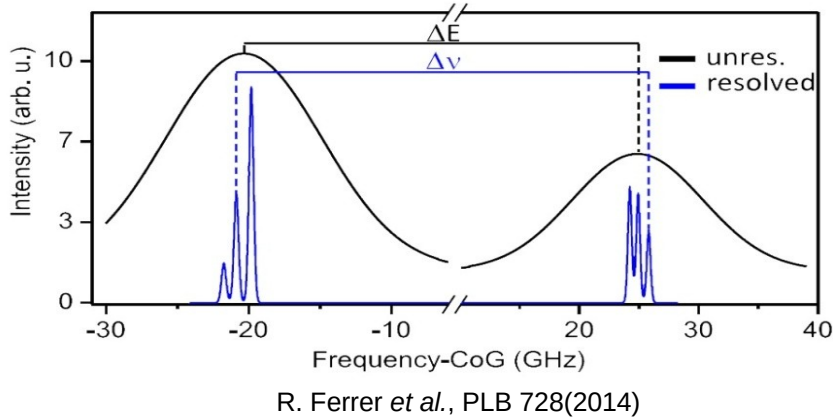
View of SEASON in GEANT4



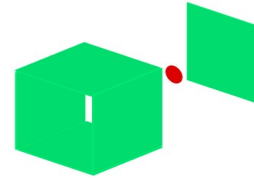
View of SEASON in GEANT4



## Goal 1: counting the laser ionized atoms to perform laser ionization spectroscopy



- Need good detection efficiency for  $\alpha$  (5 – 12 MeV) and electrons (20 – 600 keV)



Tunnel configuration  
Si detectors (BB7 from Micron)  
✓ Thickness 1 mm  
✓ Active area 64 x 64 mm<sup>2</sup>

$\alpha$  detection efficiency **81%**  
electron detection efficiency **51%**

} From Geant4 simulation

## Goal 2: perform $\alpha$ , electron, $\gamma$ decay spectroscopy

- Need good energy resolution and avoid summing effects

Energy resolution (FWHM)	15 keV ( $\alpha$ from 5 MeV to 12 MeV) 7 keV (electron from 20 keV to 600 keV)
Energy threshold	20 keV
Time resolution (FWHM)	20 ns

Si detectors (BB7 from Micron)  
✓ Thickness: 1 mm  
✓ Active area: 64 x 64 mm<sup>2</sup>  
✓ Number of strips: 32 x 32  
✓ Strip pitch: 2 mm  
✓ Dead layer: 50 nm

In order to measure both alpha and electrons with the best energy resolution

Si detector  
(BB7 from Micron)



FRONT-END



FEANICS

**Front-End Adaptive gain Integrated CircuitS**  
is a novel multi-channel ASIC in development at CEA/IRFU

Key feature:

Automatic **gain switch** depending of the signal amplitude

High gain (~50 fF) ↔ electron  
Low gain (~550 fF) ↔ alpha

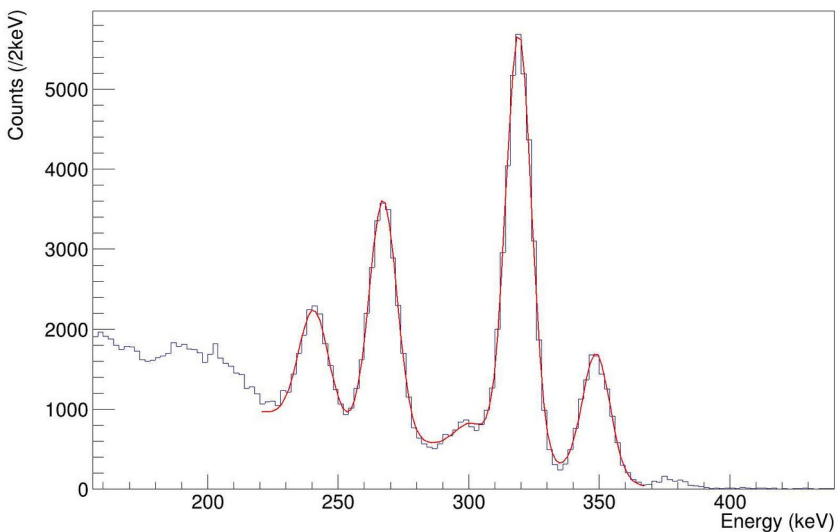
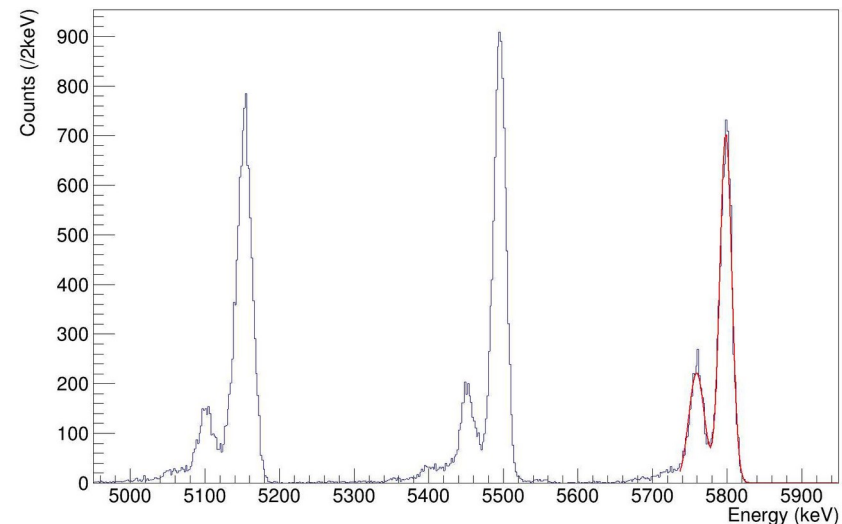
BACK-END



NUMEXO2

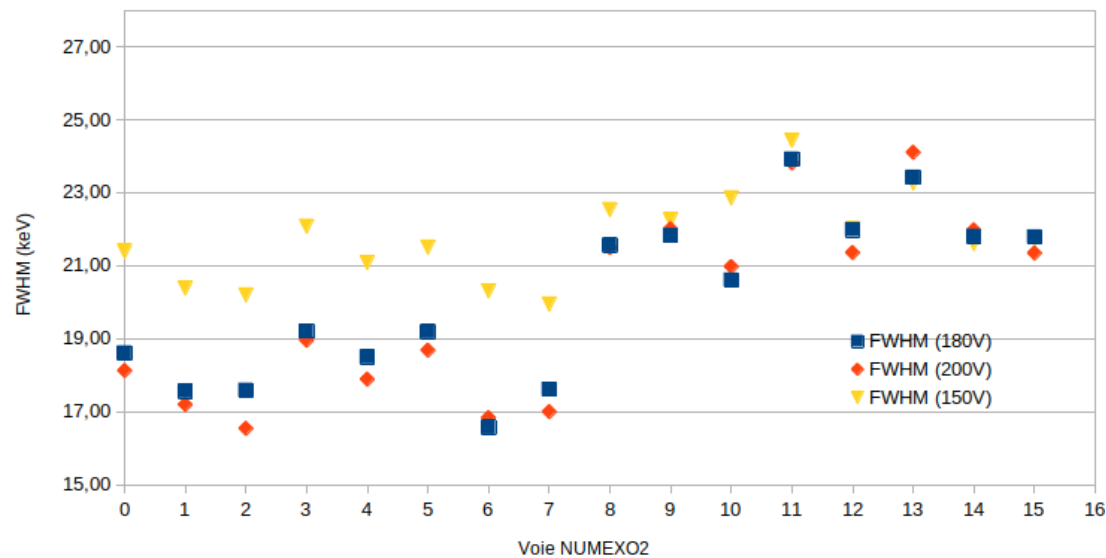
Tracks recording for  
offline processing





**3- $\alpha$  calibration source ( $^{239}\text{Pu}$ ,  $^{241}\text{Am}$ ,  $^{244}\text{Cm}$ )**

FWHM @ 5804.77keV : **18.7 keV**



**Electron source ( $^{133}\text{Ba}$ )**

FWHM @ 320.3 keV : **11.6 keV**

**Obtained with a test detector (slightly different from the final ones)**

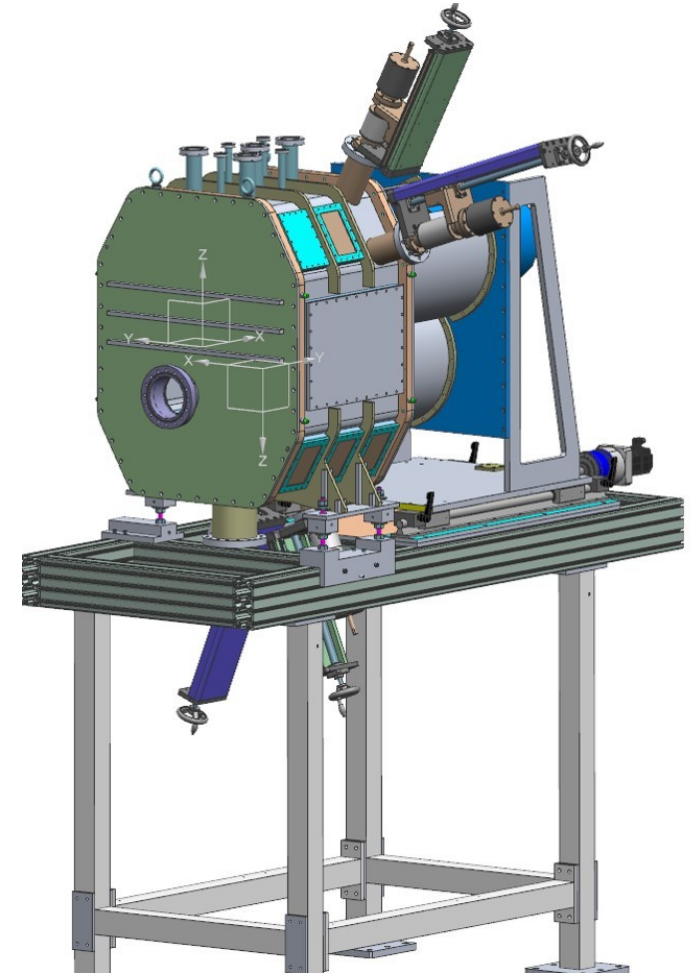
Design of SEASON is validated and the manufacturing is in progress

Electronics has been validated and the first SEASON's DSSD will arrive soon to be tested

An offline commissioning is scheduled for the summer 2023 at CEA-Saclay

An online commissioning is scheduled end of 2023 – beginning of 2024 at Jyväskylä

Then it will be set at GANIL on S3-LEB



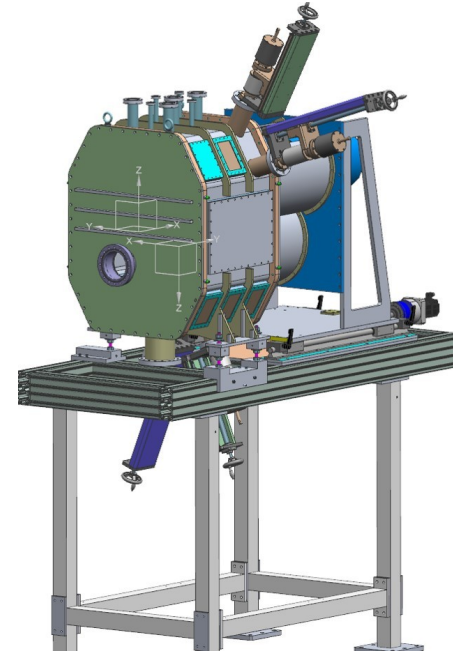


# Thank you for your attention

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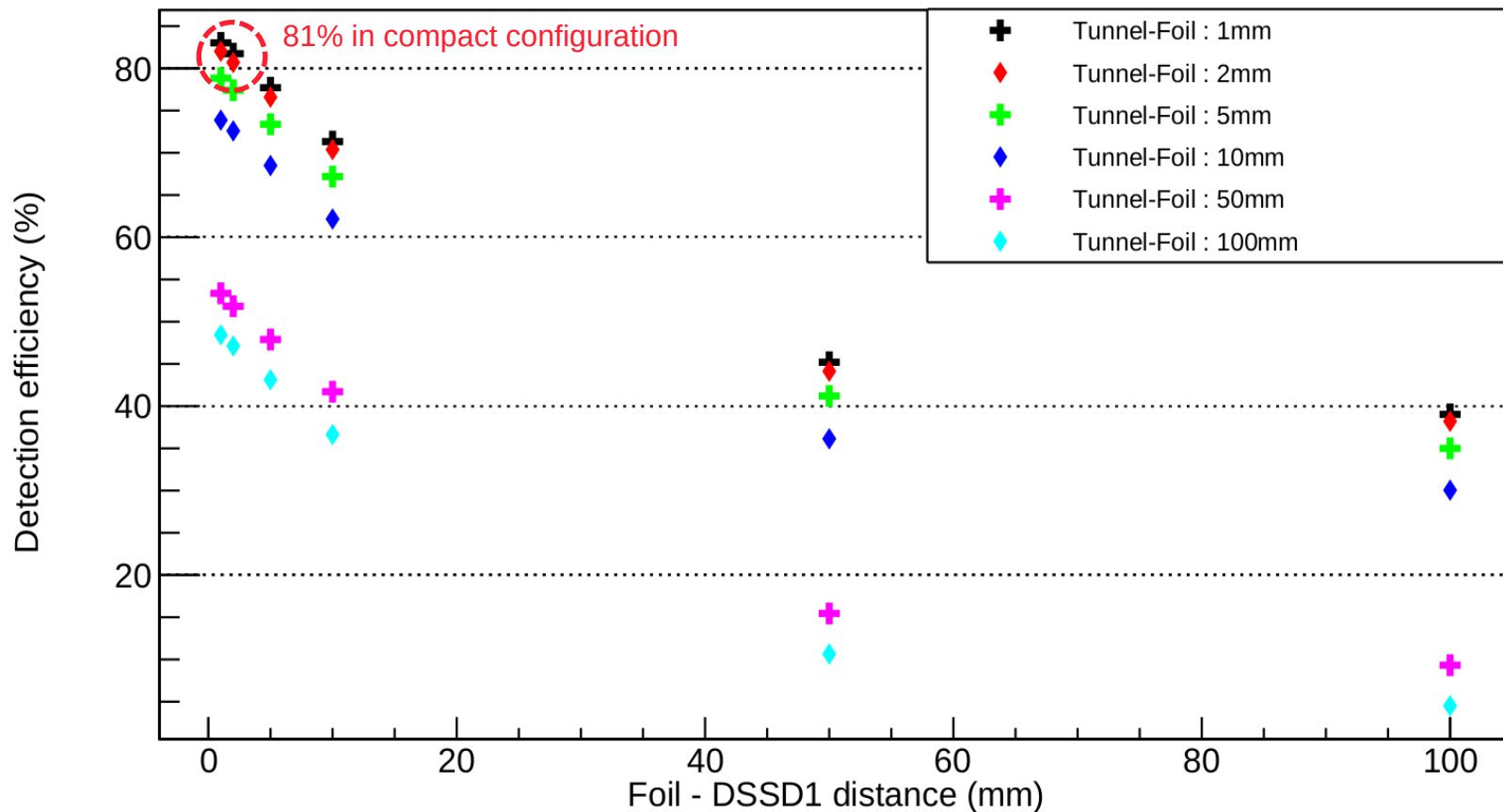


Florent Bouyjou, Sandrine Cazaux, Thomas Chaminade, Olivier Cloué, Philippe Daniel-Thomas, Antoine Drouart, Alexis Gaget, Olivier Gevin, Thomas Goigoux, Jean-Christophe Guillard, Hervé Le Provost, Jorge Mendes-Ribeiro, Gilles Minier, Julien Noury, Yann Reinert, Johan Relland, Emmanuel Rey-Herme, Arnaud Roger, Barbara Sulignano, Christophe Theisen, Damien Thisse, Marine Vandebrouck



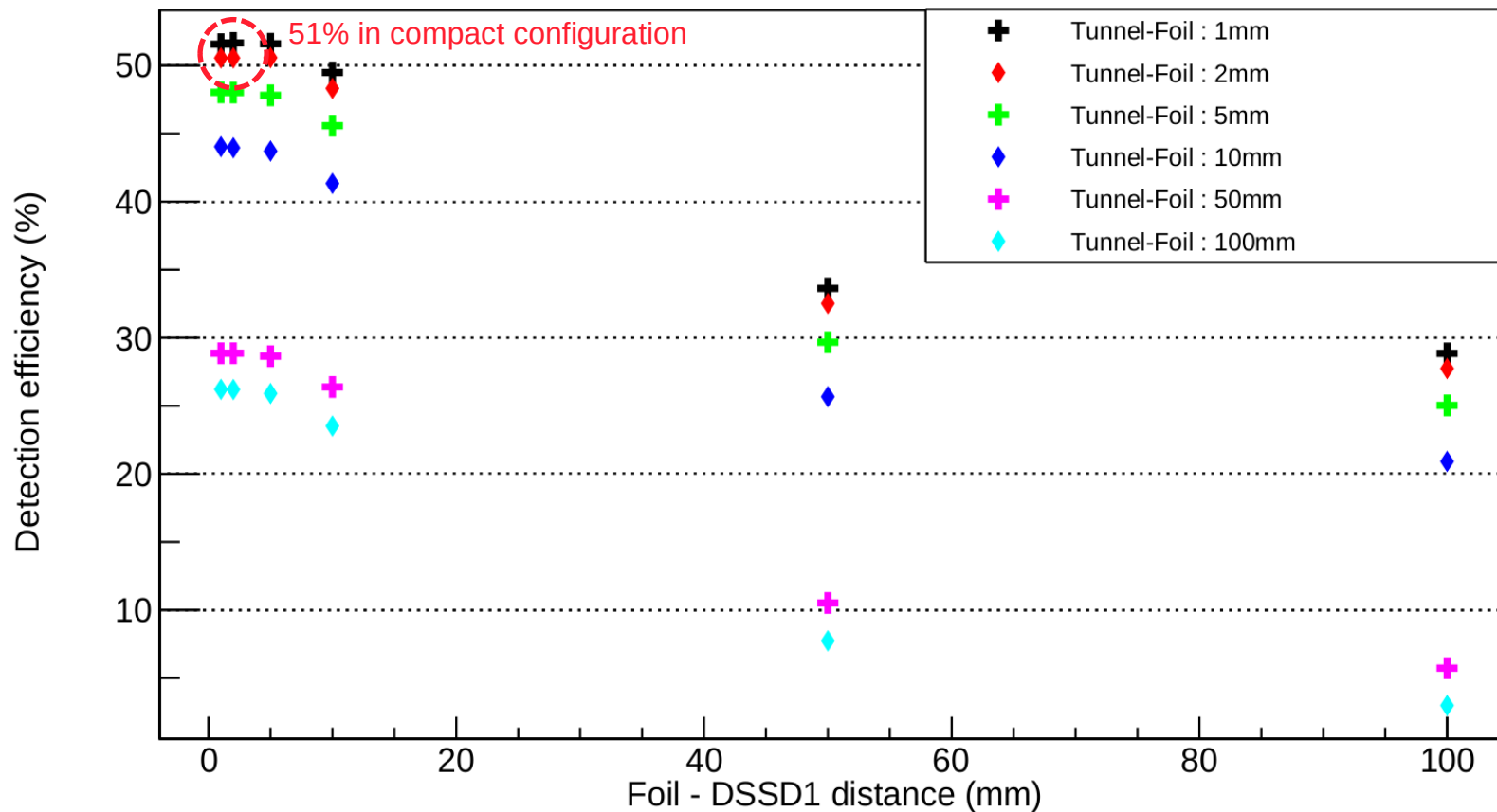
Work of T. Goigoux  
+ E. Rey-herme

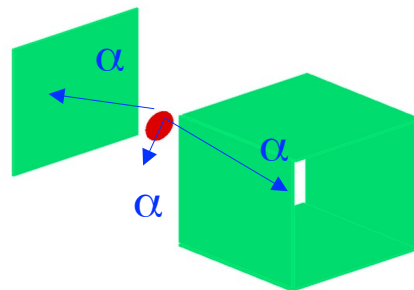
## Alpha detection efficiency (simulated)



Work of T. Goigoux  
+ E. Rey-herme

## Electron detection efficiency (simulated)





Work of T. Goigoux  
+ E. Rey-herme

